

**Fast Silicon Rectifiers**

**Schnelle Silizium Gleichrichter**

Version 2004-06-24



|                                                                                       |            |
|---------------------------------------------------------------------------------------|------------|
| Nominal current – Nennstrom                                                           | 20 A       |
| Repetitive peak reverse voltage<br>Periodische Spitzensperrspannung                   | 50...400 V |
| Plastic case<br>Kunststoffgehäuse                                                     | TO-220AC   |
| Weight approx. – Gewicht ca.                                                          | 2.2 g      |
| Plastic material has UL classification 94V-0<br>Gehäusematerial UL94V-0 klassifiziert |            |
| Standard packaging in tubes<br>Standard Lieferform in Stangen                         |            |

**Maximum ratings**

**Grenzwerte**

| Type<br>Typ | Repetitive peak reverse voltage<br>Periodische Spitzensperrspannung<br>$V_{RRM}$ [V] | Surge peak reverse voltage<br>Stoßspitzensperrspannung<br>$V_{RSM}$ [V] |
|-------------|--------------------------------------------------------------------------------------|-------------------------------------------------------------------------|
| FT 2000 A   | 50                                                                                   | 50                                                                      |
| FT 2000 B   | 100                                                                                  | 100                                                                     |
| FT 2000 D   | 200                                                                                  | 200                                                                     |
| FT 2000 G   | 400                                                                                  | 400                                                                     |

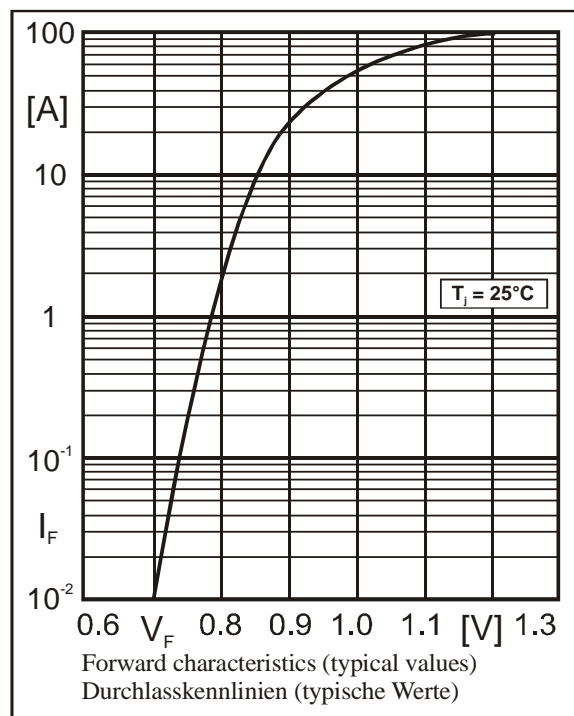
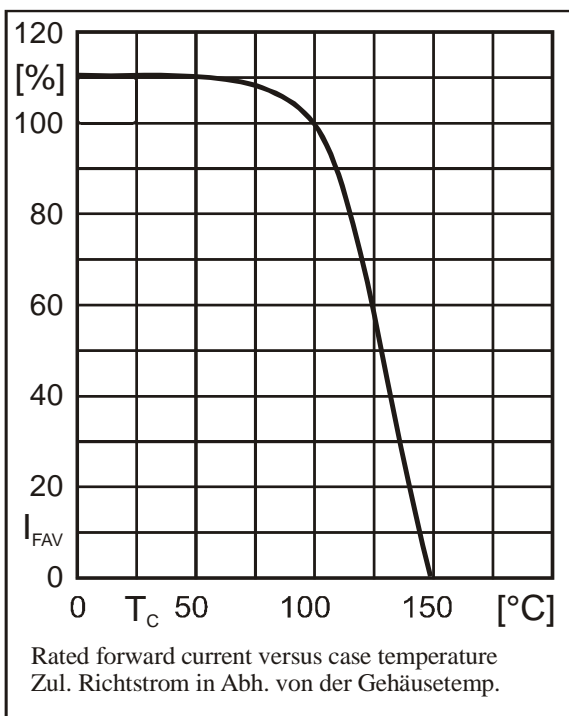
|                                                                                                      |                           |                |                                |
|------------------------------------------------------------------------------------------------------|---------------------------|----------------|--------------------------------|
| Max. average forward rectified current, R-load<br>Dauergrenzstrom in Einwegschtaltung mit R-Last     | $T_C = 100^\circ\text{C}$ | $I_{FAV}$      | 20 A                           |
| Repetitive peak forward current<br>Periodischer Spitzenstrom                                         | $f > 15\text{ Hz}$        | $I_{FRM}$      | 80 A <sup>1)</sup>             |
| Peak forward surge current, 50 Hz half sine-wave<br>Stoßstrom für eine 50 Hz Sinus-Halbwell          | $T_A = 25^\circ\text{C}$  | $I_{FSM}$      | 375 A                          |
| Peak forward surge current, 60 Hz half sine-wave<br>Stoßstrom für eine 60 Hz Sinus-Halbwell          | $T_A = 25^\circ\text{C}$  | $I_{FSM}$      | 390 A                          |
| Rating for fusing, $t < 10\text{ ms}$<br>Grenzlastintegral, $t < 10\text{ ms}$                       | $T_A = 25^\circ\text{C}$  | $i^2t$         | 680 A <sup>2</sup> s           |
| Operating junction temperature – Sperrschichttemperatur<br>Storage temperature – Lagerungstemperatur |                           | $T_j$<br>$T_s$ | – 50...+150°C<br>– 50...+175°C |

<sup>1)</sup> Valid, if leads are kept at ambient temperature at a distance of 10 mm from case  
Gültig, wenn die Anschlußdrähte in 10 mm Abstand von Gehäuse auf Umgebungstemperatur gehalten werden

**Characteristics**

**Kennwerte**

|                                                                               |                                                                                      |                     |           |                    |
|-------------------------------------------------------------------------------|--------------------------------------------------------------------------------------|---------------------|-----------|--------------------|
| Forward voltage – Durchlaßspannung                                            | $T_j = 25^\circ\text{C}$                                                             | $I_F = 20\text{ A}$ | $V_F$     | < 0.94 V           |
| Leakage current – Sperrstrom                                                  | $T_j = 25^\circ\text{C}$                                                             | $V_R = V_{RRM}$     | $I_R$     | < 25 $\mu\text{A}$ |
| Reverse recovery time<br>Sperrverzugszeit                                     | $I_F = 0.5\text{ A}$ through/über<br>$I_R = 1\text{ A}$ to/auf $I_R = 0.25\text{ A}$ |                     | $t_{rr}$  | < 200 ns           |
| Thermal resistance junction to case<br>Wärmewiderstand Sperrschicht – Gehäuse |                                                                                      |                     | $R_{thC}$ | < 2.0 K/W          |



Preliminary

Vorläufig